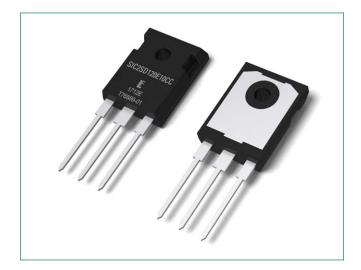


## LSIC2SD120E10CC









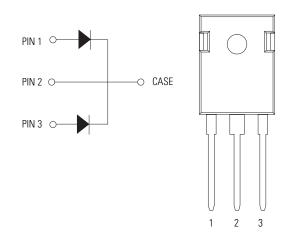
## **Description**

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. This diode series is ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

#### **Features**

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

## Circuit Diagram TO-247-3L



## **Applications**

- · Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- · Industrial motor drives
- EV charging stations

## **Environmental**

• Littelfuse "RoHS" logo = RoHS conform



• Littelfuse "HF" logo = HF Halogen Free

• Littelfuse "Pb-free" logo = Pb-free lead plating



#### **Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	-	1200	V	
DC Blocking Voltage	$V_{R}$	T <sub>J</sub> = 25 °C	1200	V	
Continuous Forward Current (Per Leg/Component)		T <sub>C</sub> = 25 °C	17.5/35	А	
	I <sub>F</sub>	T <sub>C</sub> = 135 °C	8.5/17		
		T <sub>C</sub> = 158 °C	5/10		
Non-Repetitive Forward Surge Current (Per Leg)	I <sub>FSM</sub>	$T_{\rm C}$ = 25 °C, $T_{\rm P}$ = 10 ms, Half sine pulse	40	А	
Power Dissipation (Per Leg/Component)	D	T <sub>C</sub> = 25 °C	100/200	W	
	P <sub>Tot</sub>	T <sub>c</sub> = 110 °C	43/86		
Operating Junction Temperature	TJ	-	-55 to 175	°C	
Storage Temperature	T <sub>STG</sub>	-	-55 to 150	°C	
Soldering Temperature	T <sub>sold</sub>	-	260	°C	

## **GEN2 SiC Schottky Diode** LSIC2SD120E10CC, 1200 V, 10 A, T0-247-3L

## **Electrical Characteristics (Per Leg)**

Characteristics			Value			
	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Voltage	\/	I <sub>F</sub> = 5 A, T <sub>J</sub> = 25 °C	-	1.5	1.8	V
	V <sub>F</sub>	I <sub>F</sub> = 5 A, T <sub>J</sub> = 175 °C	-	2.1		
Reverse Current		V <sub>R</sub> = 1200 V , T <sub>J</sub> = 25 °C	-	<1	100	
	I <sub>R</sub>	$V_R = 1200  V$ , $T_J = 175  ^{\circ}C$	-	5		Unit V μA pF
Total Capacitance		V <sub>R</sub> = 1 V, f =1 MHz	-	310		V μA pF
	С	$V_R = 400 \text{ V}, \text{ f} = 1 \text{ MHz}$	-	29		
		V <sub>R</sub> = 800 V, f = 1 MHz	-	21		
Total Capacitive Charge	Q <sub>c</sub>	$V_{R} = 800 \text{ V}, \ Q_{c} = \int_{C}^{V_{R}} C(V) dV$	-	30	-	nC

**Footnote:**  $T_J = +25$  °C unless otherwise specified

## **Thermal Characteristics**

Characteristics	Symbol	Conditions	Value			Unit
	Зушьог	Conditions	Min.	Тур.	Max.	Oiiit
Thermal Resistance	Reic	-	-	1.5/0.75	-	°C/W

Figure 1: Typical Foward Characteristics (Per Leg)

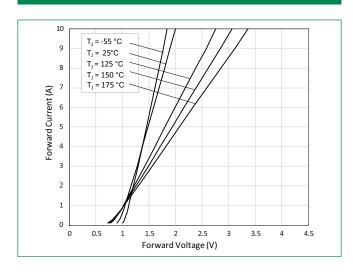


Figure 2: Typical Reverse Characteristics (Per Leg)

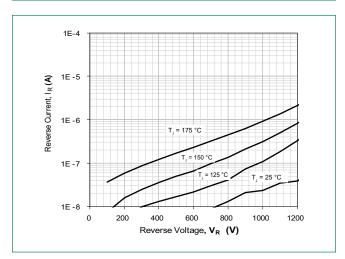




Figure 3: Power Derating (Per Leg)

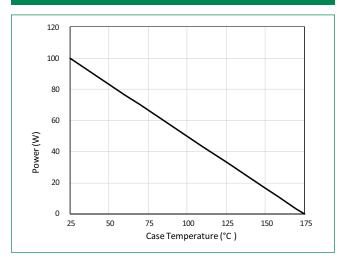


Figure 5: Capacitance vs. Reverse Voltage (Per Leg)

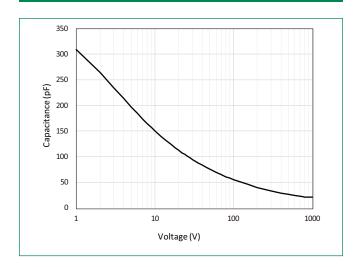


Figure 7: Stored Energy vs. Reverse Voltage (Per Leg)

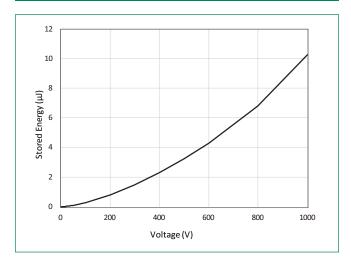


Figure 4: Current Derating (Per Leg)

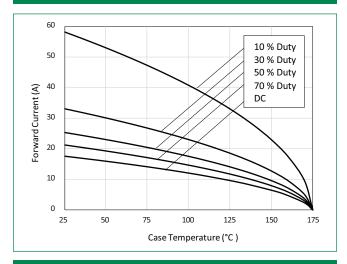


Figure 6: Capacitive Charge vs. Reverse Voltage (Per Leg)

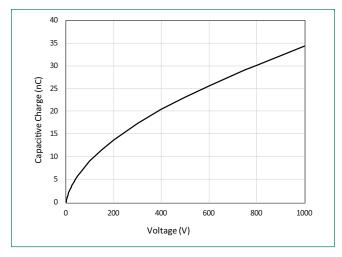
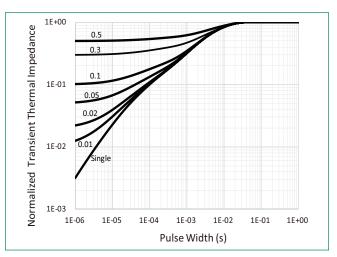
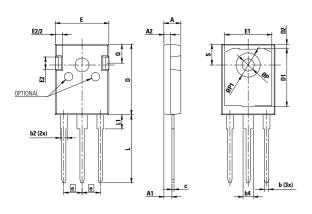


Figure 8: Transient Thermal Impedance (Per Component)



## **GEN2 SiC Schottky Diode** LSIC2SD120E10CC, 1200 V, 10 A, TO-247-3L

### Package Dimensions TO-247-3L



#### **Recommended Hole Pattern Layout**



- Notes:

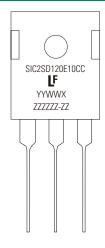
  1. Dimensions are in millimeters

  2. Dimension D, E do not include nold flash. Mold flash shall not exceed 0.127 mm per side. These measured at the outermost extreme of plastic body.

  3.0P to have a maximum draft angle of 1.5° to the top of the part with a maximum hole diameter of 0.154°.

Symbol	Millimeters				
	Min	Nom	Max		
Α	4.80	5.03	5.20		
A1	2.25	2.38	2.54		
A2	1.85	1.98	2.11		
b	0.99	-	1.40		
b2	1.65	-	2.39		
b4	2.59	-	3.43		
С	0.38	0.64	0.89		
D	20.80	20.96	21.34		
D1	13.50	-	-		
D2	0.51	1.19	1.35		
е		5.44 BSC			
E	15.75	15.90	16.13		
E1	13.06	14.02	14.15		
E2	4.19	4.32	4.83		
L	19.81	20.19	20.57		
L1	3.81	4.19	4.45		
øΡ	3.55	3.61	3.66		
øP1	7.06	7.19	7.32		
Q	5.49	5.61	6.20		
S	6.05	6.17	6.30		

## **Part Numbering and Marking System**



SIC	= SiC
2	= Gen2
SD	= Schottky Diode
400	17 L. D /

= Voltage Rating (1200 V) 120 Ε

= T0-247-3L = Current Rating (10 A) 10

CC = Common Cathode

YY = Year WW = Week

= Trace Code (Any Letter) Χ

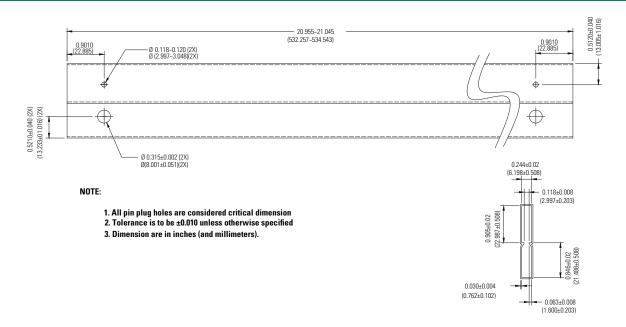
**ZZZZZZ-ZZ** = Lot Number

## **Packing Options**

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120E10CC	SIC2SD120E10CC	Tube (30pcs)	450

## GEN2 SiC Schottky Diode LSIC2SD120E10CC, 1200 V, 10 A, T0-247-3L

## **Packing Specification TO-247-3L**



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SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP
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ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA260LR-HF ACDBA1100-HF
SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573 NTE6081 SB560 PMAD1108-LF
SD103ATW-TP